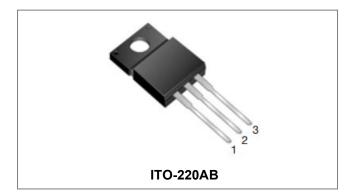


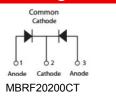
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MBRF20200CT (CTR) SCHOTTKY RECTIFIER



Circuit Diagram



Common Anode Cathode Anode Cathode MBRF20200CTR

Features

- 175°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|--|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 200 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=105°C, rectangular wave form | 10(Per Leg) 20(Per Device) | A |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse | 150 | A |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|--|------------------|---|-------|--------|-------|
| Forward Voltage Drop(Per Leg)* | V _{F1} | @10A, Pulse, T _J = 25 °C | 0.85 | 0.95 | V |
| | V _{F2} | @10A, Pulse, T _J = 125 °C | 0.75 | 0.85 | V |
| Reverse Current(Per Leg)* | I _{R1} | $@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$ | 0.001 | 1.0 | mA |
| | I _{R2} | $@V_R = rated V_{R,} T_J = 125 \circ C$ | 0.03 | 50 | mA |
| Junction Capacitance(Per Leg) | Ст | C_T @V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz | | 300 | pF |
| Series Inductance(Per Leg) | Ls | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |
| RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C) | V _{ISO} | Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction. | - | 4500 | V |
| | | Clip mounting, the epoxy body is inside the heatsink. | - | 3500 | |
| | | Screw mounting, the epoxy body is inside the heatsink. | - | 1500 | |

* Pulse width < 300 μ s, duty cycle < 2%

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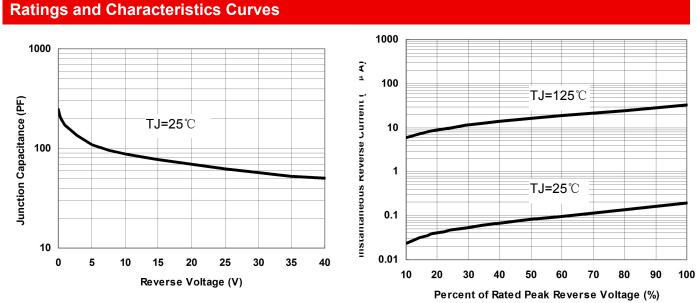


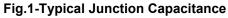
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Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|---------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +175 | °C |
| Storage Temperature | T _{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case | $R_{	ext{	heta}JC}$ | DC operation | 4.5 | °C/W |
| Approximate Weight | wt | - | 2 | g |
| Case Style | ITO-220AB | | | |







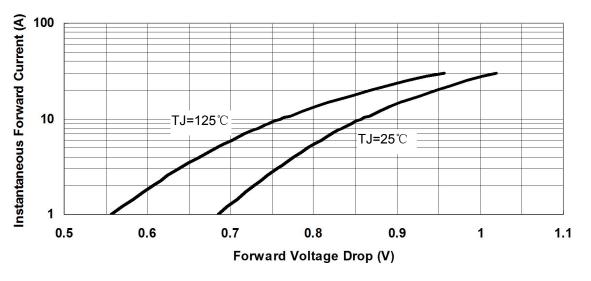


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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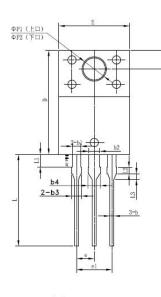


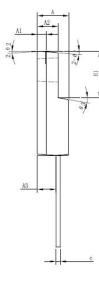
RoHS

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Mechanical Dimensions ITO-220AB

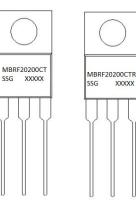
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| SYMBOL | Millimeters | | | | |
|-----------------|-------------|-------|-------|--|--|
| STWBUL | MIN. | TYP. | MAX. | | |
| A | 4.30 | 4.50 | 4.70 | | |
| A1 | 1.10 | 1.30 | 1.50 | | |
| A2 | 2.80 | 3.00 | 3.20 | | |
| A3 | 2.50 | 2.70 | 2.90 | | |
| b | 0.50 | 0.60 | 0.75 | | |
| b1 | 1.10 | 1.20 | 1.35 | | |
| b2 | 1.50 | 1.60 | 1.75 | | |
| b3 | 1.20 | 1.30 | 1.45 | | |
| b4 | 1.60 | 1.70 | 1.85 | | |
| С | 0.50 | 0.60 | 0.75 | | |
| D | 14.80 | 15.00 | 15.20 | | |
| E | 9.96 | 10.16 | 10.36 | | |
| e | | 2.55 | | | |
| e1 | | 5.10 | | | |
| H1 | 6.50 | 6.70 | 6.90 | | |
| L | 12.70 | 13.20 | 13.70 | | |
| L1 | 1.60 | 1.80 | 2.00 | | |
| L2 | 0.80 | 1.00 | 1.20 | | |
| L3 | 0.60 | 0.80 | 1.00 | | |
| ΦΡ1(上口) | 3.30 | 3.50 | 3.70 | | |
| ΦΡ2 (下口) | 2.99 | 3.19 | 3.39 | | |
| Q | 2.50 | 2.70 | 2.90 | | |
| Θ1 | | 5° | | | |
| Θ2 | | 4° | | | |
| Θ3 | | 10° | | | |
| Θ4 | | 5° | | | |
| Θ5 | | 5° | | | |

Marking Diagram



Where XXXXX is YYWWL

MBR

F

20

200

SSG

YΥ ww

L

- = Device Type
- = Package type = Forward Current (20A)
- = Reverse Voltage (200V)
- CT(CTR) = Configuration = SSG
 - = Year
 - = Week
 - = Lot Number
- Cautions: Molding resin

Ordering Information

| Device | Package | Shipping | |
|------------------|--------------------|--------------|--|
| MBRF20200CT(CTR) | ITO-220AB(Pb-Free) | 50 pcs/ tube | |

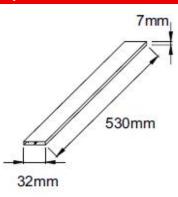
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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,0 4 ata ata ata

Tube Specification



Epoxy resin UL:94V-0



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